

# FemtoClock® NG Crystal-to-HCSL **Clock Generator**

**DATASHEET** 

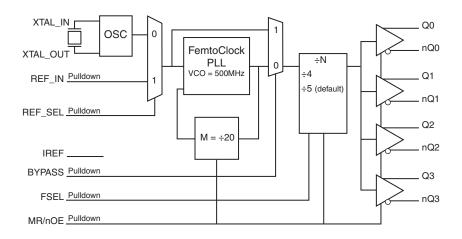
#### GENERAL DESCRIPTION

The 841604 is an optimized PCIe and sRIO clock generator. The device uses a 25MHz parallel crystal to generate 100MHz and 125MHz clock signals, replacing solutions requiring multiple oscillator and fanout buffer solutions. The device has excellent phase jitter (< 1ps rms) suitable to clock components requiring precise and low-jitter PCIe or sRIO or both clock signals. Designed for telecom, networking and industrial applications, the 841604 can also drive the high-speed sRIO and PCIe SerDes clock inputs of communication processors, DSPs, switches and bridges.

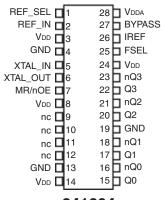
#### **F**EATURES

- Four differential clock outputs: configurable for PCIe (100MHz) and sRIO (125MHz) clock signals
- Selectable crystal oscillator interface, 25MHz, 18pF parallel resonant crystal or LVCMOS/LVTTL single-ended reference clock input
- · Supports the following output frequencies: 100MHz or 125MHz
- VCO: 500MHz
- PLL bypass and output enable
- PCI Express (2.5Gb/s) and Gen 2 (5 Gb/s) jitter compliant
- RMS phase jitter, 125MHz, using a 25MHz crystal (1.875MHz - 20MHz): 0.45ps (typical)
- Full 3.3V power supply mode
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) package

#### **BLOCK DIAGRAM**



#### PIN ASSIGNMENT



841604 28-Lead TSSOP

6.1mm x 9.7mm x 0.925mm package body G Package Top View



TABLE 1. PIN DESCRIPTIONS

Number	Name	Ту	/pe	Description
1	REF_SEL	Input	Pulldown	Reference select. Selects the input reference source. LVCMOS/LVTTL interface levels. See Table 3D.
2	REF_IN	Input	Pulldown	LVCMOS/LVTTL PLL reference clock input.
3, 8, 14, 24	V <sub>DD</sub>	Power		Core supply pins.
4, 13, 19	GND	Power		Power supply ground.
5, 6	XTAL_IN, XTAL_OUT	Input		Parallel resonant crystal interface. XTAL_OUT is the output, XTAL_IN is the input.
7	MR/nOE	Input	Pulldown	Active HIGH master reset. Active LOW output enable. When logic HIGH, the internal dividers are reset and the outputs are in high impedance (Hi-Z). When logic LOW, the internal dividers and the outputs are enabled. Asynchronous function. LVCMOS/LVTTL interface levels. See Table 3C.
9, 10, 11, 12	nc	Unused		No connect.
15, 16	Q0, nQ0	Output		Differential output pair. HCSL interface levels.
17, 18	Q1, nQ1	Output		Differential output pair. HCSL interface levels.
20, 21	Q2, nQ2	Output		Differential output pair. HCSL interface levels.
22, 23	Q3, nQ3	Output		Differential output pair. HCSL interface levels.
25	FSEL	Input	Pulldown	Output frequency select pin. LVCMOS/LVTTL interface levels. See Table 3A.
26	IREF	Output		HCSL current reference resistor output. An external fixed precision resistor (475W) from this pin to ground provides a reference current used for differential current-mode Qx/nQx clock outputs.
27	BYPASS	Input	Pulldown	Selects PLL operation/PLL bypass operation. Asynchronous function. LLVC-MOS/LVTTL interface levels. See Table 3B.
28	V <sub>DDA</sub>	Power		Analog supply pin.

NOTE: Pulldown refers to internal input resistors. See Table 2, Pin Characteristics, for typical values.

#### Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
R	Input Pulldown Resistor			51		kΩ

# Table 3A. FSEL Function Table ( $f_{ref} = 25 MHz$ )

Input		Outputs	
FSEL	N	Q0:1/nQ0:1	
0	5	VCO/5 (100MHz) PCIe (default)	
1	4	VCO/4 (125MHz) sRIO	

#### TABLE 3C. MR/nOE FUNCTION TABLE

Input				
MR/nOE	Function			
0	Outputs enabled (default)			
1	Device reset, outputs disabled (high-impedance)			

#### TABLE 3B. BYPASS FUNCTION TABLE

Input		
BYPASS PLL Configuration		
0	PLL enabled (default)	
1 PLL bypassed $(f_{OUT} = f_{REF} \div N)$		

TABLE 3D. REF\_SEL FUNCTION TABLE

Input			
REF_SEL Input Reference			
0	XTAL (default)		
1	REF_IN		



#### ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V<sub>DD</sub> 4.6V

Inputs,  $V_{_{DD}}$  -0.5V to  $V_{_{DD}}$  + 0.5V

Outputs,  $V_{\odot}$  -0.5V to  $V_{DD}$  + 0.5V

Package Thermal Impedance,  $\theta_{_{JA}}$  64.5°C/W (0 mps) Storage Temperature, T -65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 4A. Power Supply DC Characteristics,  $V_{DD} = 3.3V \pm 5\%$ , Ta = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Core Supply Voltage		3.135	3.3	3.465	V
V <sub>DDA</sub>	Analog Supply Voltage		V <sub>DD</sub> - 0.15	3.3	V <sub>DD</sub>	V
l <sub>DD</sub>	Power Supply Current				87	mA
DDA	Analog Supply Current				15	mA

Table 4B. LVCMOS / LVTTL DC Characteristics,  $V_{_{DD}}$  = 3.3V±5%, Ta = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V <sub>IH</sub>	Input High Volt	age		2		V + 0.3	V
V	Input Low Volta	age		-0.3		0.8	V
II		REF_IN, REF_SEL, BYPASS, MR/nOE, FSEL				150	μΑ
II		REF_IN, REF_SEL, BYPASS, MR/nOE, FSEL		-5			μΑ

#### TABLE 5. CRYSTAL CHARACTERISTICS

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fı	ındamenta	I	
Frequency			25		MHz
Equivalent Series Resistance (ESR)				50	Ω
Shunt Capacitance				7	pF

NOTE: Characterized using an 18pF parallel resonant crystal.



**Table 6. AC Characteristics,**  $V_{pp} = 3.3V \pm 5\%$ , TA = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
£	Output Fraguenay	VCO/5		100		MHz
MAX	Output Frequency	VCO/4		125		MHz
+::+/ <i>(X</i> )	RMS Phase Jitter (Random); NOTE 1	100MHz, (1.875MHz - 20MHz)		0.36		ps
tjit(Ø)	RMS Phase Jiller (Random), NOTE 1	125MHz, (1.875MHz - 20MHz)		0.45		ps
т	Phase Jitter Peak-to-Peak; NOTE 2	100MHz, (1.2MHz – 50MHz), 10° samples, 25MHz crystal input		12.81		ps
j	Fridse Siller Feak-10-Feak, NOTE 2	125MHz, (1.2MHz – 62.5MHz), 10° samples, 25MHz crystal input		12.30		ps
т	Phase Jitter RMS; NOTE 3	100MHz, 10° samples, 25MHz crystal input		1.32		ps rms
REFCLK_HF_RMS	Friase Sitter Fivis, NOTE 3	125MHz, 10° samples, 25MHz crystal input		1.19		ps rms
tjit(cc)	Cycle-to-Cycle Jitter; NOTE 4				50	ps
tsk(o)	Output Skew; NOTE 4, 5				75	ps
Rise Edge Rate	Rising Edge Rate; NOTE 6, 7		0.6		4	V/ns
_	Falling Edge Rate; NOTE 6, 7		0.6		4	V/ns
V <sub>RB</sub>	Ringback Voltage; NOTE 6, 8		-100		100	mV
V <sub>MAX</sub>	Absolute Max. Output Voltage; NOTE 9, 10				1150	mV
V	Absolute Min. Output Voltage; NOTE 9, 11		-300			mV
V <sub>CROSS</sub>	Absolute Crossing Voltage; NOTE 9, 12, 13		250		550	mV
DV <sub>CROSS</sub>	Total Variation of V <sub>cross</sub> over all edges; NOTE 9, 12, 14				140	mV
odc	Output Duty Cycle; NOTE 6, 15		48		52	%
T	Power-up Stable Clock Output; NOTE 6, 8		500			ps
t_	PLL Lock Time				90	ms

NOTE: All specifications are taken at 100MHz and 125MHz.

NOTE 1: Please refer to the Phase Noise Plot.

NOTE 2: RMS jitter after applying system transfer function. See IDT Application Note, PCI Express Reference Clock Requirements. Maximum limit for PCI Express is 86ps peak-to-peak.

NOTE 3: RMS jitter after applying system transfer function. The pole frequencies for H1 and H2 for PCIe Gen 2 are 8-16MHz and 5-16MHz.

See IDT Application Note, PCI Express Reference Clock Requirements.Maximum limit for PCI Express Generation 2 is 3.1ps rms.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 5: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential cross points.

NOTE 6: Measurement taken from differential waveform.

NOTE 7: Measurement from -150mV to +150mV on the differential waveform (derived from Qx minus nQx).

The signal must be monotonic through the measurement region for rise and fall time. The 300mV measurement window is centered on the differential zero crossing. See Parameter Measurement Information Section.

NOTE 8:  $T_{\text{STABLE}}$  is the time the differential clock must maintain a minimum ±150mV differential voltage after rising/falling edges before it is allowed to drop back into the  $V_{\text{BB}}$  ±100 differential range. See Parameter Measurement Information Section.

NOTE 9: Measurement taken from single ended waveform.

NOTE 10: Defined as the maximum instantaneous voltage including overshoot. See Parameter Measurement Information Section.

NOTE 11: Defined as the minimum instantaneous voltage including undershoot. See Parameter Measurement Information Section.

NOTE 12: Measured at crossing point where the instantaneous voltage value of the rising edge of Qx equals the falling edge of nQx.

See Parameter Measurement Information Section.

NOTE 13: Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing.

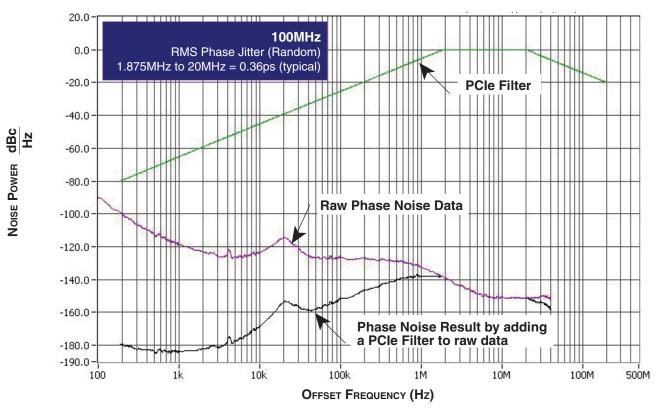
Refers to all crossing points for this measurement. See Parameter Measurement Information Section.

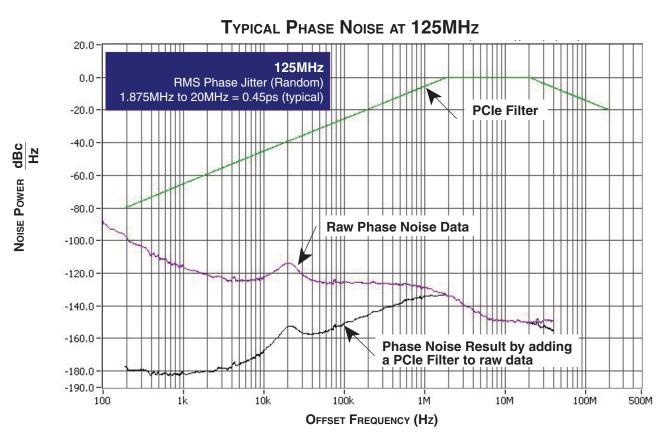
NOTE 14: Defined as the total variation of all crossing voltage of rising Qx and falling nQx. This is the maximum allowed variance in the V<sub>cross</sub> for any particular system. See Parameter Measurement Information Section.

NOTE 15: Input duty cycle must be 50%.



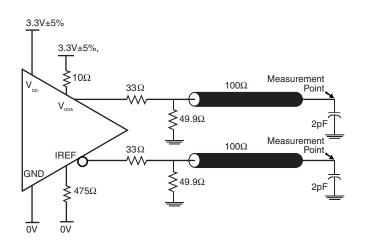
#### Typical Phase Noise at 100MHz

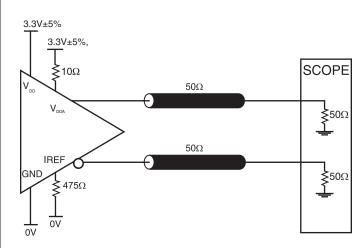






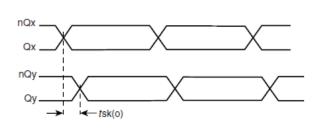
# PARAMETER MEASUREMENT INFORMATION



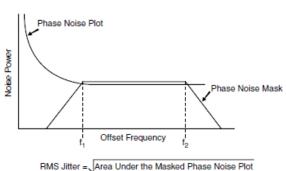


This load condition is used for  $I_{_{DD}}$ , tsk(o), and tjit measurements.

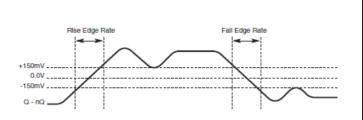
#### 3.3V HCSL OUTPUT LOAD AC TEST CIRCUIT



#### 3.3V HCSL OUTPUT LOAD ACTEST CIRCUIT



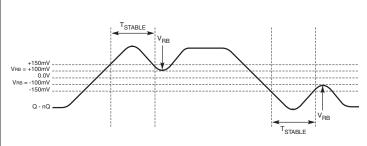
#### **OUTPUT SKEW**



#### DIFFERENTIAL MEASUREMENT POINTS FOR RISE/FALL TIME

# RMS Jitter = Area Under the Masked Phase Noise Plot

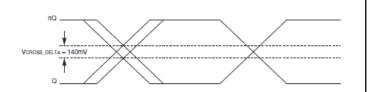
#### **RMS PHASE JITTER**



DIFFERENTIAL MEASUREMENT POINTS FOR RINGBACK



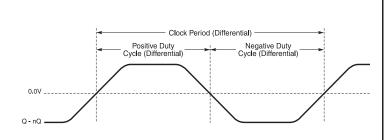
# PARAMETER MEASUREMENT INFORMATION, CONTINUED

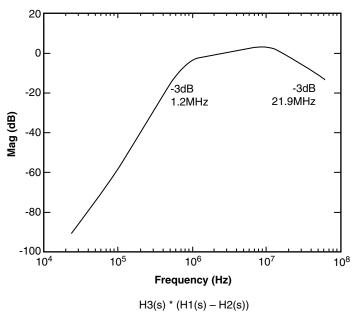




#### SINGLE-ENDED MEASUREMENT POINTS FOR DELTA CROSS POINT

# SINGLE-ENDED MEASUREMENT POINTS FOR ABSOLUTE CROSS POINT/SWING





DIFFERENTIAL MESUREMENT POINTS FOR DUTY CYCLE PERIOD

COMPOSITE PCIe TRANSFER FUNCTION



#### APPLICATION INFORMATION

#### Power Supply Filtering Techniques

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The 841604 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{\tiny DD}$  and  $V_{\tiny DDA}$  should be individually connected to the power supply plane through vias, and  $0.01\mu F$  bypass capacitors should be used for each pin. Figure 1 illustrates this for a generic V $_{\tiny DD}$  pin and also shows that V $_{\tiny DDA}$  requires that an additional  $10\Omega$  resistor along with a  $10\mu F$  bypass capacitor be connected to the V $_{\tiny DDA}$  pin.

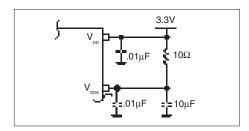


FIGURE 1. POWER SUPPLY FILTERING

#### RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS

#### INPUTS:

#### **CRYSTAL INPUTS**

For applications not requiring the use of the crystal oscillator input, both XTAL\_IN and XTAL\_OUT can be left floating. Though not required, but for additional protection, a 1k $\Omega$  resistor can be tied from XTAL\_IN to ground.

#### REF\_IN INPUT

For applications not requiring the use of the reference clock, it can be left floating. Though not required, but for additional protection, a  $1k\Omega$  resistor can be tied from the REF\_IN to ground.

#### LVCMOS CONTROL PINS

All control pins have internal pull-downs; additional resistance is not required but can be added for additional protection. A  $1k\Omega$  resistor can be used.

#### **OUTPUTS:**

#### DIFFERENTIAL OUTPUTS

All unused differential outputs can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.



#### CRYSTAL INPUT INTERFACE

The 841604 has been characterized with 18pF parallel resonant crystals. The capacitor values shown in *Figure 2* below were

determined using a 25MHz, 18pF parallel resonant crystal and were chosen to minimize the ppm error.

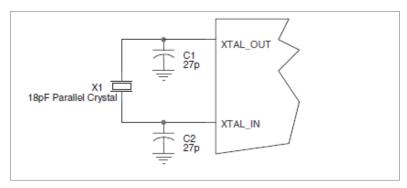


FIGURE 2. CRYSTAL INPUT INTERFACE

#### LVCMOS TO XTAL INTERFACE

The XTAL\_IN input can accept a single-ended LVCMOS signal through an AC couple capacitor. A general interface diagram is shown in *Figure 3*. The XTAL\_OUT pin can be left floating. The input edge rate can be as slow as 10ns. For LVCMOS inputs, it is recommended that the amplitude be reduced from full swing to half swing in order to prevent signal interference with the power rail and to reduce noise. This configuration requires that the output

impedance of the driver (Ro) plus the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of two ways. First, R1 and R2 in parallel should equal the transmission line impedance. For most  $50\Omega$  applications, R1 and R2 can be  $100\Omega$ . This can also be accomplished by removing R1 and making R2  $50\Omega$ .

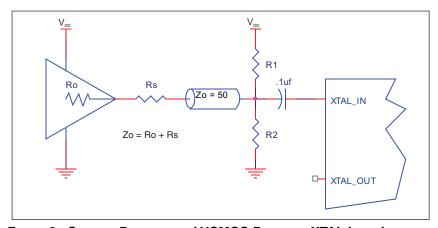


FIGURE 3. GENERAL DIAGRAM FOR LVCMOS DRIVER TO XTAL INPUT INTERFACE



#### SCHEMATIC EXAMPLE

Figure 4 shows an example of 841604 application schematic. In this example, the device is operated at  $V_{\tiny DD} = 3.3V$ . The 18pF parallel resonant 25MHz crystal is used. The C1 = 27pF and C2 = 27pF are recommended for frequency accuracy. For different board layout,

the C1 and C2 may be slightly adjusted for optimizing frequency accuracy. Two examples of HCSL terminations are shown in this schematic. The decoupling capacitors should be located as close as possible to the power pin.

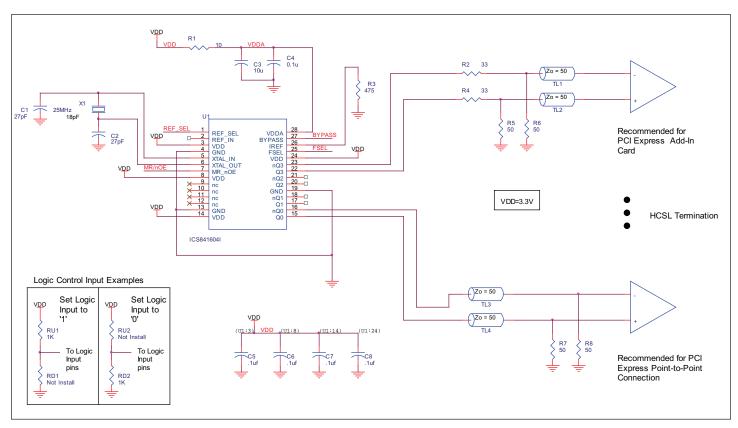


FIGURE 4. 841604 SCHEMATIC EXAMPLE



#### RECOMMENDED TERMINATION

Figure 5A is the recommended termination for applications which require the receiver and driver to be on a separate PCB. All traces should be  $50\Omega$  impedance.

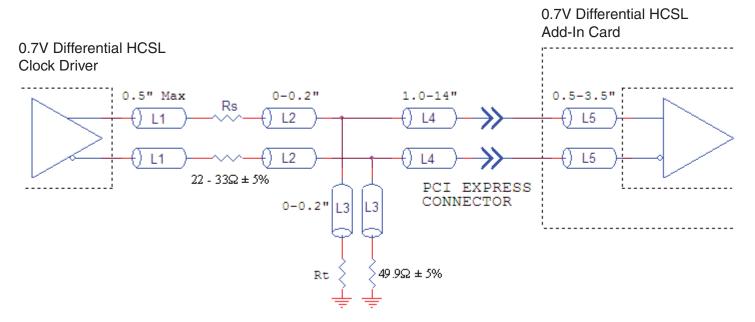


FIGURE 5A. RECOMMENDED TERMINATION

Figure 5B is the recommended termination for applications which require a point to point connection and contain the driver and

receiver on the same PCB. All traces should all be  $50\Omega$  impedance.

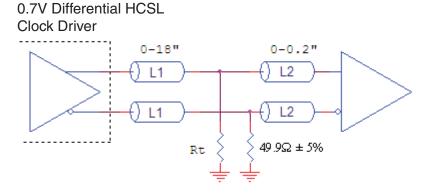


FIGURE 5B. RECOMMENDED TERMINATION



#### Power Considerations

This section provides information on power dissipation and junction temperature for the 841604. Equations and example calculations are also provided.

#### 1. Power Dissipation.

The total power dissipation for the ICS41604l is the sum of the core power plus the analog plus the power dissipated in the load(s). The following is the power dissipation for  $V_{nn} = 3.3V + 5\% = 3.465V$ , which gives worst case results.

**NOTE:** Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)<sub>MAX</sub> =  $V_{DD,MAX}$  \* ( $I_{DD,MAX}$  +  $I_{DDA}$ ) = 3.465V \* (87mA + 15mA) = **353.43mW**
- Power (outputs)<sub>MAX</sub> = 44.5mW/Loaded Output pair
   If all outputs are loaded, the total power is 4 \* 44.5mW = 178mW

**Total Power**  $_{MAX}$  (3.465V, with all outputs switching) = 353.43mW + 178mW = **531.43mW** 

#### 2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS™ devices is 125°C.

The equation for Tj is as follows: Tj =  $\theta_{JA}$  \* Pd\_total + T<sub>A</sub>

Tj = Junction Temperature

 $\theta_{\mbox{\tiny JA}} = Junction\mbox{-to-Ambient Thermal Resistance}$ 

Pd\_total = Total Device Power Dissipation (example calculation is in Section 1 above)

T<sub>A</sub> = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance  $\theta_{JA}$  must be used. Assuming no air flow and a multi-layer board, the appropriate value is 64.54°C/W per Table 7 below.

Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:  $85^{\circ}\text{C} + 0.531\text{W} * 64.5^{\circ}\text{C/W} = 119.2 ^{\circ}\text{C}$ . This is below the limit of  $125^{\circ}\text{C}$ .

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

Table 7. Thermal Resistance  $\theta_{\text{JA}}$  for 28-Pin TSSOP, Forced Convection

# θ<sub>JA</sub> by Velocity (Meters per Second) 0 1 2.5 Multi-Layer PCB, JEDEC Standard Test Boards 64.5°C/W 60.4°C/W 58.5°C/W



#### 3. Calculations and Equations.

The purpose of this section is to calculate power dissipation on the IC per HCSL output pair.

HCSL output driver circuit and termination are shown in Figure 6.

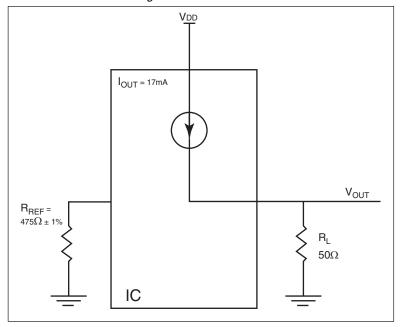


FIGURE 6. HCSL DRIVER CIRCUIT AND TERMINATION

HCSL is a current steering output which sources a maximum of 17mA of current per output. To calculate worst case on-chip power dissipation, use the following equations which assume a  $50\Omega$  load to ground.

The highest power dissipation occurs when  $V_{\tiny DD}$  is HIGH.

Power = 
$$(V_{\text{DD\_HIGH}} - V_{\text{OUT}}) * I_{\text{OUT}}$$
, since  $V_{\text{OUT}} = I_{\text{OUT}} * R_{\text{L}}$   
=  $(V_{\text{DD\_HIGH}} - I_{\text{OUT}} * R_{\text{L}}) * I_{\text{OUT}}$   
=  $(3.465V - 17mA * 50\Omega) * 17mA$ 

Total Power Dissipation per output pair = 44.5mW



# **RELIABILITY INFORMATION**

Table 8.  $\theta_{_{JA}}$  vs. Air Flow Table for 28 Lead TSSOP

# $\theta_{\mbox{\tiny JA}}$ by Velocity (Meters per Second)

0

1

2.5

Multi-Layer PCB, JEDEC Standard Test Boards

64.5°C/W 60.4°C/W

58.5°C/W

#### **Transistor Count**

The transistor count for 841604 is: 2785

# PACKAGE OUTLINE AND DIMENSIONS

PACKAGE OUTLINE - G SUFFIX FOR 28 LEAD TSSOP

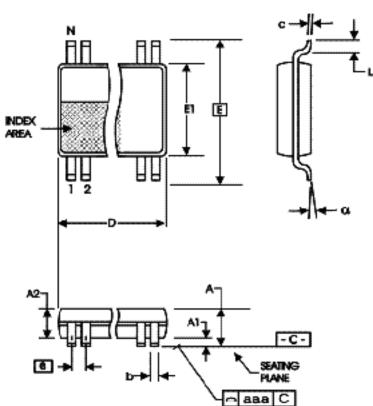


TABLE 9. PACKAGE DIMENSIONS

SYMBOL	Millim	neters
STINIBUL	Minimum	Maximum
N	2	8
Α		1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
С	0.09	0.20
D	9.60	9.80
E	8.10 E	BASIC
E1	6.00	6.20
е	0.65 E	BASIC
L	0.45	0.75
α	0°	8°
aaa		0.10

Reference Document: JEDEC Publication 95, MO-153



#### Table 10. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
841604AGILF	ICS841604AGILF	28 Lead "Lead-Free" TSSOP	tube	-40°C to 85°C
841604AGILFT	ICS841604AGILF	28 Lead "Lead-Free" TSSOP	tape & reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.



#### REVISION HISTORY SHEET

Rev	Table	Page	Description of Change	Date
А	T10	15	Ordering Information - removed leaded devices.	4/17/15
			Updated data sheet format.	



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